

# **TDA7479**

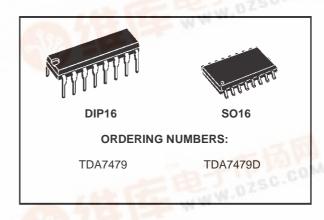
# SINGLE CHIP RDS DEMODULATOR + FILTER

- VERY HIGH RDS DEMODULATION QUALITY WITH IMPROVED DIGITAL SIGNAL PROC-**ESSING**
- HIGH PERFORMANCE, 57KHz BANDPASS FILTER (8th ORDER)
- FILTER ADJUSTMENT FREE AND WITHOUT **EXTERNAL COMPONENTS**
- PURELY DIGITAL RDS DEMODULATION WITHOUT EXTERNAL COMPONENTS
- ARI (SK INDICATION) AND RDS SIGNAL QUALITY OUTPUT
- 4.332MHz CRYSTAL OSCILLATOR (8.664 and 17.328MHz OPTIONAL)
- LOW NOISE CMOS TECHNOLOGY
- LOW RADIATION

#### **DESCRIPTION**

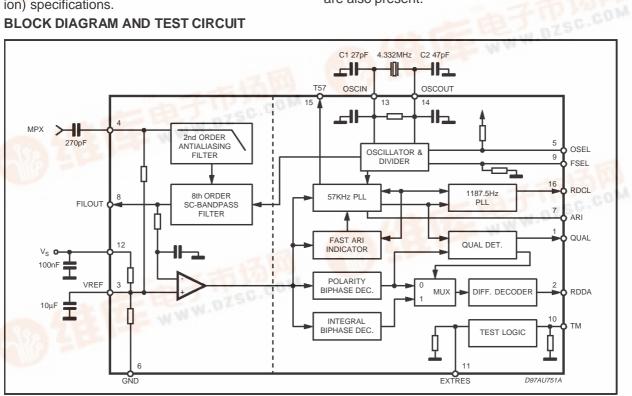
The TDA7479 recovers the additional inaudible RDS information which is transmitted by FM radio broadcasting stations and operates in accordance with the EBU (European Broadcasting Union) specifications.

#### **BLOCK DIAGRAM AND TEST CIRCUIT**



The device is made up of two sections: a cascaded antialiasing + switched capacitors bandpass filter for precise RDS band selection and a demodulating section that performs the extraction od RDS data stream (RDDA) and clock (RDCL), to be furher processed by a suitable RDS decoder.

Outputs for RDS signal quality and ARI indication are also present.





### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	-0.3 to 7	V
T <sub>op</sub>	Operating Temperature Range	-40 to 85	°C
T <sub>sta</sub>	Storage Temperature	-55 to 150	°C

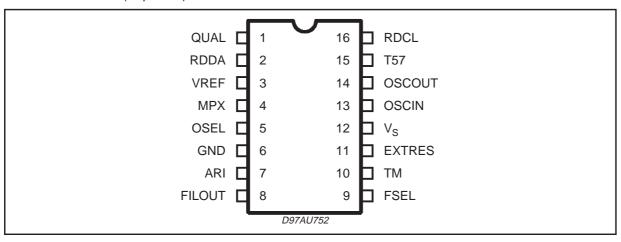
#### **THERMAL DATA**

Symbol	Description	DIP16	SO16	Unit
R <sub>th i-case</sub>	Thermal Resistance Junction-case Max.	100	200	°C/W

### **PIN DESCRIPTION**

N° pin	Name	Description				
1	QUAL	Output for signal quality indication (High = good)				
2	RDDA	RDS data output				
3	VREF	Reference voltage				
4	MPX	RDS input signal				
5	OSEL	Oscillator selector pin:	<ul> <li>open, closed to V<sub>S</sub> = quartz oscillator</li> <li>closed to GND=external driven</li> </ul>			
6	GND	Ground				
7	ARI	Output for ARI indication:	<ul> <li>high when RDS+ARI are present</li> <li>high when only ARI is present</li> <li>low when only RDS is present</li> <li>undefined when nos signal is present</li> </ul>			
8	FILOUT	Filter output				
9	FSEL	Frequency selector pin:	-100K to $V_S$ = 17.328MHz - open = 4.332MHz - closed to $V_S$ = 8.664MHz			
10	TM	Test mode pin:	<ul> <li>open = normal operation</li> <li>closed to V<sub>S</sub> = testmode</li> </ul>			
11	EXTRES	Reset pin:	<ul><li>open=run mode</li><li>closed to V<sub>S</sub> = reset condition</li></ul>			
12	Vs	Supply voltage				
13	OSCIN	Oscillator input				
14	OSCOUT	Oscillator output				
15	T57	Testing output pin: 57kHz	clock output			
16	RDCL	RDS clock output 1187.5H	Z			

### PIN CONNECTION (Top View)



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### **THERMAL DATA**

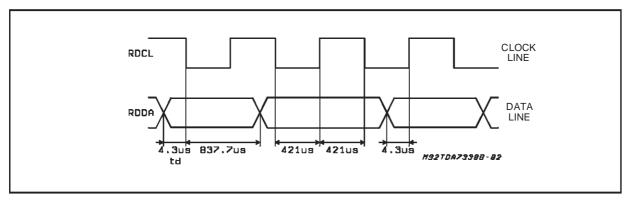
Symbol	Description	DIP20	SO20	Unit
R <sub>th j-amb</sub>	Thermal Resistance Junction-Ambient Max	100	200	°C/W

# **ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, $V_{S} = 5V$ , unless otherwise specified).

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply voltage		4.5	5	5.5	V
Is	Supply current			7.5	11.0	mA
FILTER						
f <sub>C</sub>	Center frequency		56.5	57	57.5	kHz
BW	3dB Bandwidth		2.5	3	3.5	kHz
G	Gain	f = 57kHz	18	20	22	dB
А	Attenuation	$\Delta f \pm 4kHz$	18	22		dB
		f = 38kHz	50	60		dB
		f = 67kHz	35	45		dB
Rı	Input impedance of MPX		80	120	150	ΚΩ
R∟	Load impedance on FILOUT		1			MΩ
S/N	Signal to noise ratio	V <sub>IN</sub> = 3mV <sub>RMS</sub>	30	40		dB
V <sub>IN</sub>	MPX input signal	f = 19kHz; T3 ≤ 40dB(1) f = 57kHz (RDS+ ARI)			1000 50	mV <sub>RMS</sub> mV <sub>RMS</sub>
V <sub>REF</sub>	Reference			V <sub>S</sub> /2		V
DEMODUL	LATOR		•			
Input pins Input pin (	(EXTRES, FSEL, TM)		all with in			
i iiibar biii (	USEL)		With	n internal	l pull up i	resistor
I <sub>PD</sub>	Input Current	V <sub>IN</sub> = 5V (pull-down input)	15	n internal	1 pull up	resistor μA
	T ·	$V_{IN} = 5V$ (pull-down input) $V_{IN} = 0V$ (pull-up input)		ninterna	· ·	I
I <sub>PD</sub>	Input Current		15	0.8 · V <sub>S</sub>	30	μА
I <sub>PD</sub>	Input Current Input Current		15 -25		30 -10	μA μA
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub>	Input Current Input Current Input voltage high	V <sub>IN</sub> = 0V (pull-up input)	15 -25	0.8 · V <sub>S</sub>	30 -10	μA μA V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub>	Input Current Input Current Input voltage high Input voltage low	V <sub>IN</sub> = 0V (pull-up input)	15 -25	0.8 · V <sub>S</sub>	30 -10	μA μA V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin V <sub>OH</sub>	Input Current Input Current Input voltage high Input voltage low s (RDCL, RDDA, ARI, QUAL, T5)	V <sub>IN</sub> = 0V (pull-up input)	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub>	30 -10	μΑ μΑ V V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin	Input Current Input Current Input voltage high Input voltage low s (RDCL, RDDA, ARI, QUAL, T5) Ouput voltage high Output voltage low	$V_{IN} = 0V$ (pull-up input)  7) $I_L = 0.5 \text{mA}$	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub>	30 -10 0.3 · Vs	μA μA V V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin V <sub>OH</sub> V <sub>OL</sub>	Input Current Input Current Input voltage high Input voltage low s (RDCL, RDDA, ARI, QUAL, T5) Ouput voltage high Output voltage low	$V_{IN} = 0V$ (pull-up input)  7) $I_L = 0.5 \text{mA}$	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub>	30 -10 0.3 · Vs	μA μA V V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin V <sub>OH</sub> V <sub>OL</sub> OSCILLAT	Input Current Input Current Input voltage high Input voltage low s (RDCL, RDDA, ARI, QUAL, T5) Ouput voltage high Output voltage low	$V_{IN} = 0V$ (pull-up input)  7) $I_L = 0.5 \text{mA}$ $I_L = 0.5 \text{mA}$	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub>	30 -10 0.3 · Vs	μA μA V V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin V <sub>OH</sub> V <sub>OL</sub> OSCILLAT	Input Current Input Current Input voltage high Input voltage low s (RDCL, RDDA, ARI, QUAL, T5 Ouput voltage high Output voltage low  FOR Input level OSCIN pin	$V_{IN} = 0V$ (pull-up input)  7) $I_L = 0.5 \text{mA}$ $I_L = 0.5 \text{mA}$ OSEL = open circuit	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub>	30 -10 0.3 · Vs	μA μA V V V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin V <sub>OH</sub> V <sub>OL</sub> OSCILLAT	Input Current Input Current Input Voltage high Input voltage low s (RDCL, RDDA, ARI, QUAL, T5) Ouput voltage high Output voltage low  FOR Input level OSCIN pin Input level OSCIN pin	V <sub>IN</sub> = 0V (pull-up input)  7)  I <sub>L</sub> = 0.5mA  I <sub>L</sub> = 0.5mA  OSEL = open circuit  OSEL = open circuit	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub> 4.6 0.4	30 -10 0.3 · Vs	μA μA V V V V V V
I <sub>PD</sub> I <sub>PU</sub> V <sub>IH</sub> V <sub>IL</sub> Output pin V <sub>OH</sub> V <sub>OL</sub> OSCILLAT VCLL VCLH	Input Current Input Current Input voltage high Input voltage low S (RDCL, RDDA, ARI, QUAL, T5) Ouput voltage high Output voltage low  FOR Input level OSCIN pin Input level OSCIN pin Amplitude OSCOUT Amplitude OSCIN	V <sub>IN</sub> = 0V (pull-up input)  7)  I <sub>L</sub> = 0.5mA  I <sub>L</sub> = 0.5mA  OSEL = open circuit	15 -25 0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub> 0.2 · V <sub>S</sub> 4.6 0.4	30 -10 0.3 · Vs	μA μA V V V V V V V V V V V V V V V V V

<sup>(1)</sup> The 3rd harmonic (57kHz) must be less than -40dB with respect to the input signal plus gain.

Figure 1. RDS timing diagram



#### **OUTPUT TIMING**

The RDS (1187.5Hz) output clock on RDCL line is synchronized to the incoming data.

According to the internal PLL lock condition data change can result on the falling or on the rising clock edge. (see Fig. 1)

Whichever clock edge is used by the decoder (rising or falling edge) the data will remain valid for 416.7 µsec after the clock transition.

#### **OSCILLATOR CONTROLS (FSEL, OSEL)**

Three different crystal frequencies can be used. The adaption of the internal clock divider to the external crystal is achieved via the input pin FSEL. See the following table for reference:

Crystal	FSEL (pin configuration)
4.332MHz	connected to GND or open
8.664MHz	connected to Vs
17.328MHz	external resistor of 100K to Vs

A special mode is introduced to reduce EMI. With pin OSEL connected to GND the internal oscillator is switched off and an external sinusoidal frequency could be applied on OSCIN. The peak to peak voltage of this signal can be reduced down to 60mV

In this mode the frequency selection via FSEL is still active.

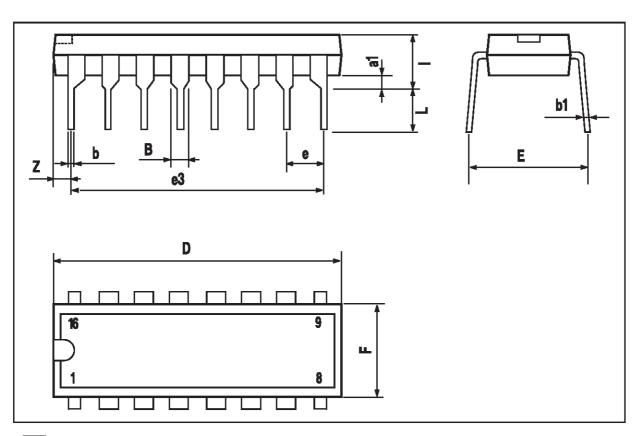
Suggested values of C1 and C2 are shown in the following table:

Crystal	C1	C2
4.332MHz	27pF	47pF
8.664MHz 17.328MHz	27pF 27pF	-

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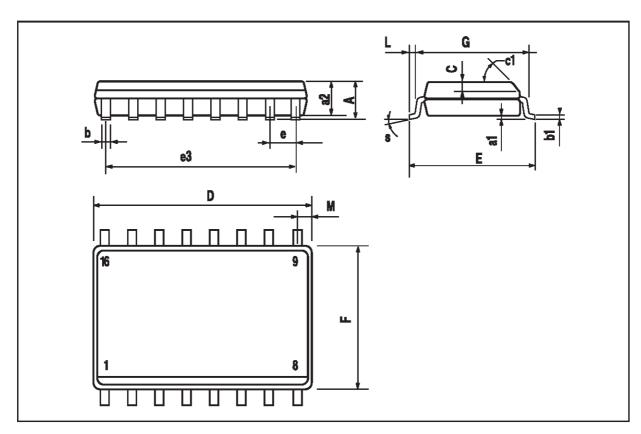
## **DIP16 PACKAGE MECHANICAL DATA**

DIM.		mm			inch		
<b>-</b>	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
a1	0.51			0.020			
В	0.77		1.65	0.030		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
Е		8.5			0.335		
е		2.54			0.100		
e3		17.78			0.700		
F			7.1			0.280	
I			5.1			0.201	
L		3.3			0.130		
Z			1.27			0.050	



## **SO16 PACKAGE MECHANICAL DATA**

DIM.	mm			inch		
Dilvi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			2.65			0.104
a1	0.1		0.3	0.004		0.012
a2			2.45			0.096
b	0.35		0.49	0.014		0.019
b1	0.23		0.32	0.009		0.013
С		0.5			0.020	
c1			45°	(typ.)		
D	10.1		10.5	0.398		0.413
Е	10.0		10.65	0.394		0.419
е		1.27			0.050	
e3		8.89			0.350	
F	7.4		7.6	0.291		0.299
L	0.5		1.27	0.020		0.050
М			0.75			0.030
S	8° (max.)					



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